

Date: - 2 Feb, 2004

Data Sheet Issue: 1

Provisional Data

Extra Fast Recovery Diode

Type F0800LC180

Old Type No.: F0400LC180

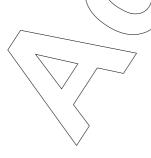
Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{RRM}	Repetitive peak reverse voltage, (note 1)	1800	V
V_{RSM}	Non-repetitive peak reverse voltage, (note 1)	1900	V

	OTHER RATINGS	MAXIMUM LIMITS	UNITS
$I_{F(AV)M}$	Maximum average forward current, T _{sink} =55°C, (note 2)	775	Α
$I_{F(AV)M}$	Maximum average forward current. T _{sink} =85°C, (hote 2)	368	Α
$I_{F(AV)M}$	Maximum average forward. T _{sink} =85°C, (note 3)	210	Α
I _{F(RMS)}	Nominal RMS forward current, T _{sink} =25°C _v (note 2)	1545	Α
I _{f(d.c.)}	D.C. forward current, T _{sink} =25°C, (note 4)	1304	Α
I _{FSM}	Peak non-repetitive surge t _p =10 ms, \forall_{RM} =60% \forall_{RRM} , (note 5)	7630	Α
I _{FSM2}	Peak non-repetitive surge t _p =10ms, V _{RM} ≤10V, (note 5)	8400	Α
l ² t	I ² t capacity for fusing t _p =10ms, V _{RM} =60%V _{RRM} , (note 5)	291×10 ³	A^2s
l ² t	I ² t capacity for fusing t _p ≠10ms, V _{RM} ≤10V, (note 5)	353×10 ³	A ² s
T _{j op}	Operating temperature range	-40 to +125	°C
T _{stg}	Storage temperature range	-40 to +150	°C

Notes:-

- 1) De-rating factor of 0.13% per °C is applicable for T_i below 25°C.
- 2) Double side cooled, single phase; 50Hz, 180° half-sinewave.
- 3) Single side cooled, single phase; 50Hz, 180° half-sinewave.
- 4) Double side cooled.
- 5) Half-sinewaye, 125°C T_j initial.
- 6) Current (I_F) ratings have been calculated using V_{T0} and r_T (see page 2).



Characteristics

	PARAMETER	MIN.	TYP.	MAX.	TEST CONDITIONS (Note 1)	UNITS	
V_{FM}	Maximum peak forward voltage	-	-	2.05	I _{FM} =800A	V	
VFM	waximum peak lorward voltage	-	-	2.60	I _{FM} =1600A	V	
V _{T0}	Threshold voltage	-	-	1.494		V	
r⊤	Slope resistance	-	-	0.692	Current range 775A-2325A (Note 2)	mΩ	
V _{T01}	Threshold voltage	-	-	1.498		V	
r _{T1}	Slope resistance	-	-	0.690	Current range 800A-2400A	mΩ	
\/	Maximum forward recovery voltage	-	-	82	di/dt = 1000A/µs	V	
V _{FRM}	waximum forward recovery voitage	-	-	68/	di/dt = 1000A/µs, T _j =25°C	V	
l	Peak reverse current	-	-	1/50 /	Rated V _{RRM}	mA	
IRRM	-eak reverse current	-	-	30	Rated V _{RRM} , T _j =25°C	IIIA	
Q _{ra}	Recovered charge, 50% Chord	-	200	-	1 000A + F00W dildt 4000A/W	μC	
t _{rr}	Reverse recovery time, 50% Chord	-	1.1	-	I _{FM} =800A, t _p =500μs, di/dt=1000A/μs, V _r =500V, 50% Chord. (note 3)	μs	
I _{rm}	Reverse recovery current	-	380	-	VI-500V, 50 % Chord. (note 5)	Α	
Q _{ra}	Recovered charge, 50% Chord	-	55/	65	1000A t 500up di/dt 200A/up	μC	
t _{rr}	Reverse recovery time, 50% Chord	-	1.0	[//<	Π _{RM} =1000A, t _p =500μs, di/dt=200A/μs,	μs	
I _{rm}	Reverse recovery current	-	120		V=50V, 50% Chord.	А	
R	Thermal resistance, junction to heatsink	- /	<i></i>	0.032	Double side cooled	K/W	
R_{thJK}	JK Thermal resistance, junction to heatsink		(- <	0.064	Single side cooled	rv/vv	
F	Mounting force	10	\-	20		kN	
W_t	Weight	-	340	-		g	

Notes:-

- Unless otherwise indicated T_j=125°C.
 V_{T0} and r_T were used to calculate the current ratings illustrated on page one.
 Figures 3-6 were compiled using these conditions.
- 4) For other clamp forces consult/factory.



Notes on Ratings and Characteristics

1.0 Voltage Grade Table

				-	
Voltage Grade	V _{RRM} (V)	V _{RSM} (V)	I I	(V)	$\left\langle \right\rangle$
18	1800	1900		900 \	

2.0 De-rating Factor

A blocking voltage de-rating factor of 0.13% per °C is applicable to this device for T_i/below 25°C.

3.0 ABCD Constants

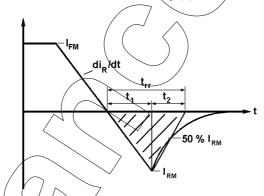
These constants (applicable only over current range of V_F characteristic in Figure 1) are the coefficients of the expression for the forward characteristic given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

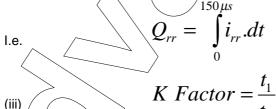
where I_F = instantaneous forward current.

4.0 Reverse recovery ratings

(i) Q_{ra} is based on 50% I_{rm} chord as shown in Fig. (a) below.



(ii) Q_{rr} is based on a 150 µs integration time.





5.0 Reverse Recovery Loss

The following procedure is recommended for use where it is necessary to include reverse recovery loss.

From waveforms of recovery current obtained from a high frequency shunt (see Note 1) and reverse voltage present during recovery, an instantaneous reverse recovery loss waveform must be constructed. Let the area under this waveform be E joules per pulse. A new sink temperature can then be evaluated from:

$$T_{\textit{SINK}} = T_{\textit{J(MAX)}} - E \cdot \left[k + f \cdot R_{\textit{thJK}}\right]$$

Where $k = 0.2314 \, (^{\circ}\text{C/W})/\text{s}$

E =Area under reverse loss waveform per pulse in joules (W.s.)

f = Rated frequency in Hz at the original sink temperature.

 R_{thJK} = d.c. thermal resistance (°C/W)

The total dissipation is now given by:

$$W_{(tot)} = W_{(original)} + E \cdot f$$

NOTE 1 - Reverse Recovery Loss by Measurement

This device has a low reverse recovered charge and peak reverse recovery current. When measuring the charge, care must be taken to ensure that:

- (a) AC coupled devices such as current transformers are not affected by prior passage of high amplitude forward current.
- (b) A suitable, polarised, clipping circuit must be connected to the input of the measuring oscilloscope to avoid overloading the internal amplifiers by the relatively high amplitude forward current signal.
- (c) Measurement of reverse recovery waveform should be carried out with an appropriate critically damped snubber, connected across diode anode to cathode. The formula used for the calculation of this snubber is shown below:

$$R^2 = 4 \cdot \frac{V_r}{C_S \cdot \frac{di}{dt}}$$

Where: $V_r = Commutating source voltage$

C_s = Snubber capacitance

R = Snubber resistance

6.0 Snubber Components

When selecting snubber components, care must be taken not to use excessively large values of snubber capacitor or excessively small values of snubber resistor. Such excessive component values may lead to device damage due to the large resultant values of snubber discharge current. If required, please consult the factory for assistance.

7.0 Computer Modelling Parameters

7.1 Device Dissipation Calculations

$$I_{AV} = \frac{-V_o + \sqrt{V_o + 4 \cdot ff^2 \cdot r_s \cdot W_{AV}}}{2 \cdot ff^2 \cdot r_s}$$

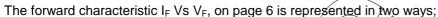
Where $V_{T0} = 1.494 \text{V}$, $r_T = 0.692 \text{m}\Omega$

ff = form factor (normally unity for fast diode applications)

$$W_{_{AV}} = \frac{\Delta T}{R_{_{th}}}$$

$$\Delta T = T_{j(MAX)} - T_K$$





- (i) the well established Vo and rs tangent used for rating purposes and
- (ii) a set of constants A, B, C, and D forming the coefficients of the representative equation for V_F in terms of I_F given below:

$$V_F = A + B \cdot \ln(I_F) + C \cdot I_F + D \cdot \sqrt{I_F}$$

The constants, derived by curve fitting software, are given in this report for hot characteristics. The resulting values for V_F agree with the true device characteristic over a current range, which is limited to that plotted.

	25°C Coefficients	125°C Coefficients
A	0.5500522	-1.3840139
/ B(0.195326	0.6344428
\C' /	3.6494×10 ⁻⁴	9.83261×10 ⁻⁴
D	6.89769×10 ⁻³	-0.05634619

8.0 Frequency Ratings

The curves illustrated in figures 8 to 16 are for guidance only and are superseded by the maximum ratings shown on page 1.

9.0 Square wave ratings

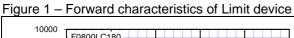
These ratings are given for load component rate of rise of forward current of 100 and 500 A/µs.

10.0 Duty cycle lines

The 100% duty cycle is represented on all the ratings by a straight line. Other duties can be included as parallel to the first.



Curves



F0800LC180 AD Issue 1 25°C 125°C Instantaneous forward current - $I_{\text{FM}}\left(A\right)$ 1000 100 0 2 3 Maximum instantaneous forward voltage - V_{FM} (V)

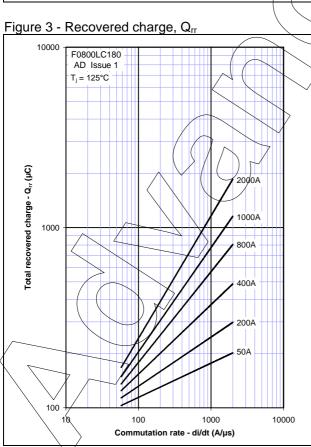
Figure 2 – Maximum forward recovery voltage F0800LC180 AD Issue 1 forward recovery voltage - VFRM (V) 25°C 100 Maximum 10

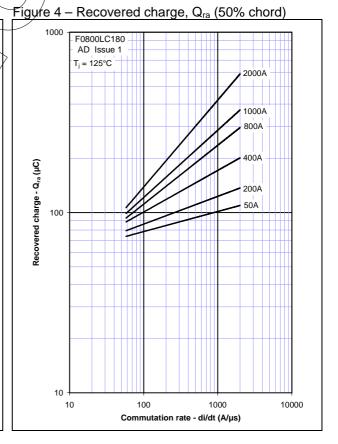
100

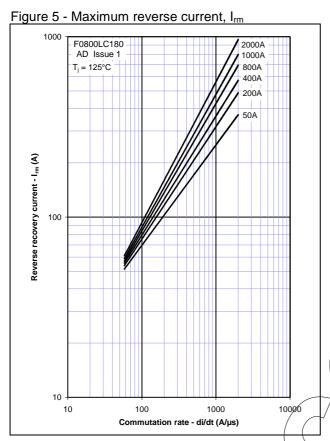
Rate of rise of forward current - di/dt (A/µs)

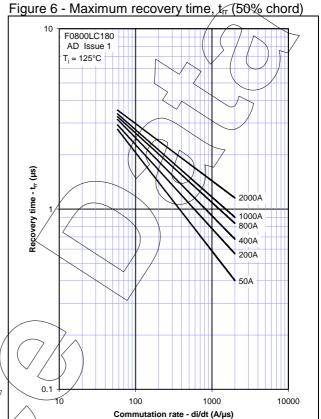
1000

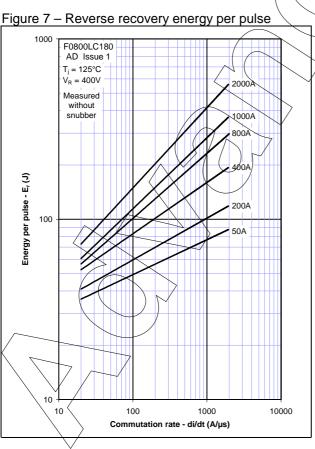
10000

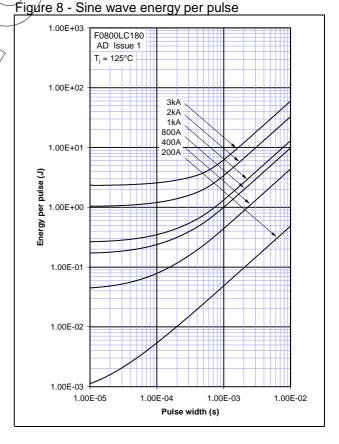


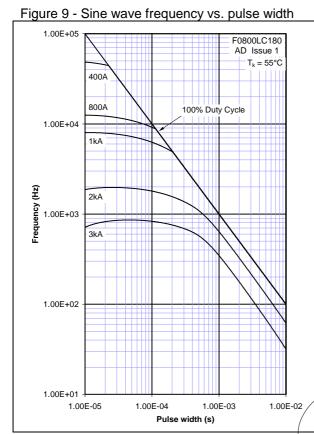


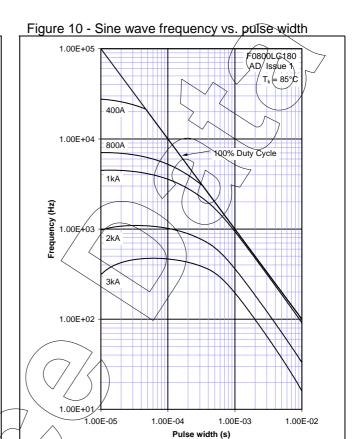


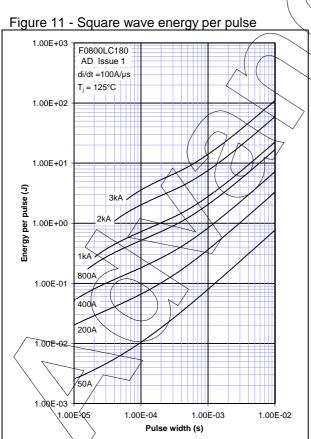












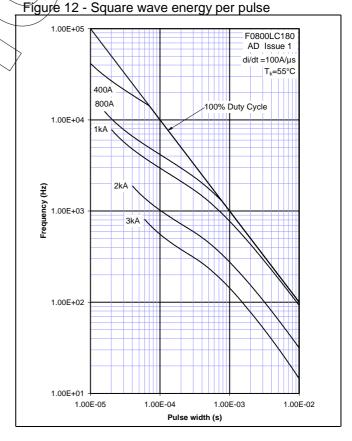


Figure 13 - Square wave frequency vs. pulse width

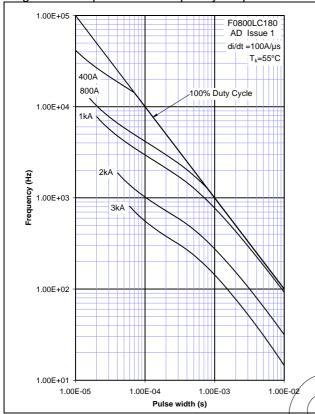
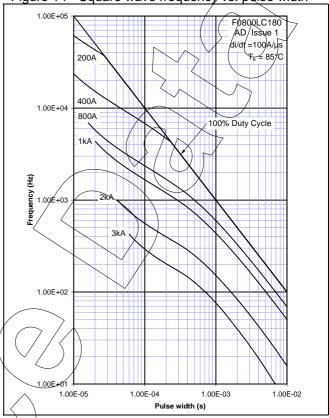


Figure 14 - Square wave frequency vs. pulse width



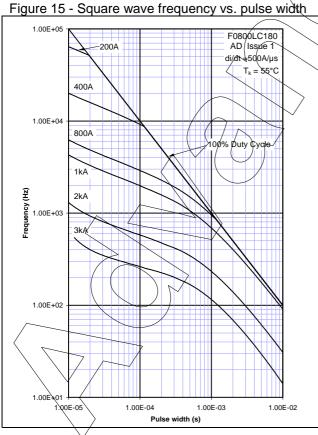
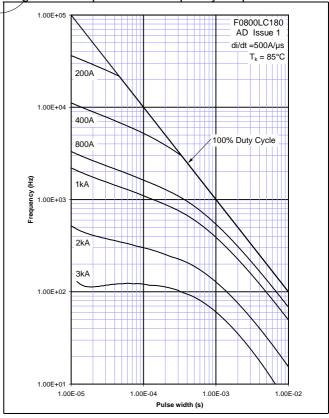


Figure 16 - Square wave frequency vs. pulse width



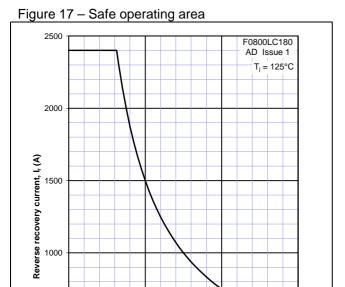


Figure 18 – Transient thermal impedance

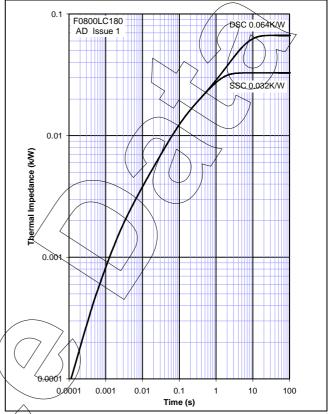
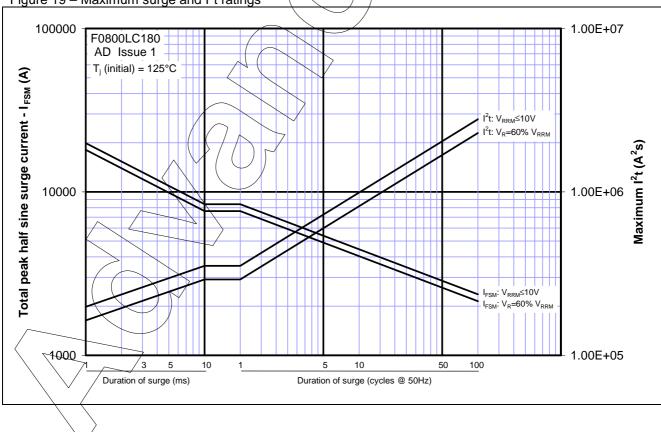


Figure 19 – Maximum surge and I²t ratings

500

500

0

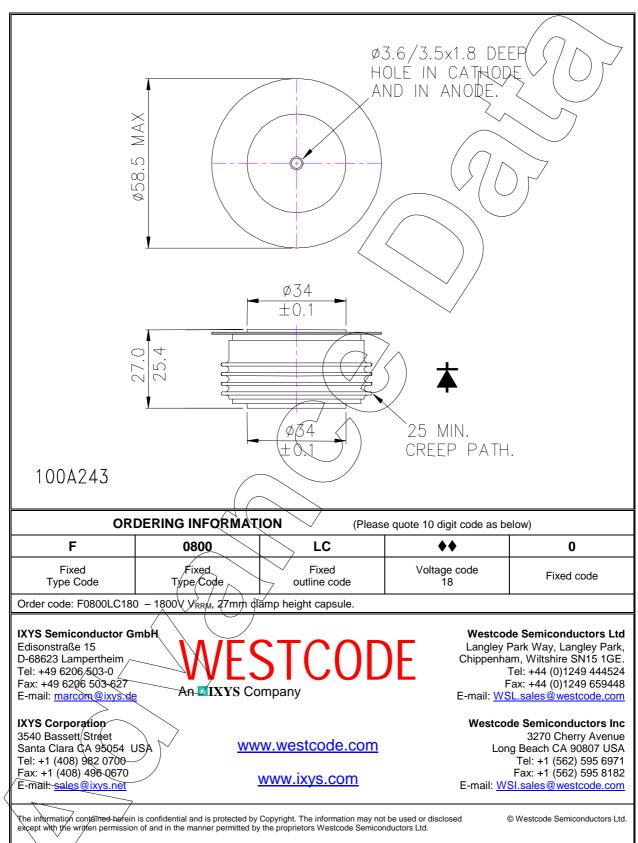


1500

1000

Reverse recovery voltage, V_r (V)

Outline Drawing & Ordering Information



In the interest of product improvement, Westcode reserves the right to change specifications at any time without prior notice.

Devices with a softix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.